# VS-8ETH03S-M3, VS-8ETH03-1-M3

**Vishay Semiconductors** 

# Hyperfast Rectifier, 8 A FRED Pt®

#### **FEATURES**

- · Hyperfast recovery time
- · Low forward voltage drop
- · Low leakage current
- 175 °C operating junction temperature



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

Vishay Semiconductors 300 V series are the state of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

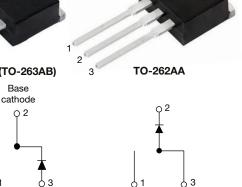
ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V <sub>RRM</sub>		300	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 155 °C	8	٨			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	100	A			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J$ = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	300	-	-			
Forward voltage	V <sub>F</sub>	I <sub>F</sub> = 8 A	-	1.0	1.25	V		
Forward voltage		I <sub>F</sub> = 8 A, T <sub>J</sub> = 125 °C	-	0.83	1.00			
Poveroo lookago ourrent		$V_{R} = V_{R}$ rated	-	0.02	20			
Reverse leakage current	I <sub>R</sub>	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	6.0	200	μA		
Junction capacitance	CT	V <sub>R</sub> = 300 V	-	31	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		

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N/C



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VS-8ETH03S-M3

Anode

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VS-8ETH03-1-M3

Anode

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	8 A					
V <sub>R</sub>	300 V					
V <sub>F</sub> at I <sub>F</sub>	0.83 V					
t <sub>rr</sub>	35 ns					
T <sub>J</sub> max.	175 °C					
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					



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DYNAMIC RECOVERY CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = -$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = -50 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$			35			
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	27	-	ns		
		T <sub>J</sub> = 125 °C		-	40	-			
Deck receiver ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 8 A dI <sub>F</sub> /dt = - 200 A/μs V <sub>R</sub> = 200 V	-	2.2	-	A		
Peak recovery current		T <sub>J</sub> = 125 °C		-	5.3	-			
Davience and a second shares	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	30	-	nC		
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	106	-	пс		

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction to case per leg	R <sub>thJC</sub>		-	1.45	2.5			
Thermal resistance, junction to ambient per leg	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.2	-			
Maiabt			-	2.0	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style D <sup>2</sup> PAK (TO-263AB)	8ETH03S					
Marking device		Case style TO-262	8ETH03-1					

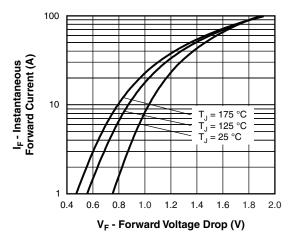


Fig. 1 - Typical Forward Voltage Drop Characteristics

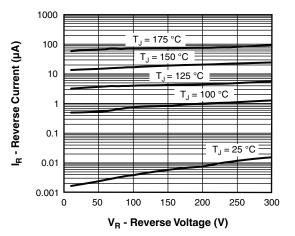


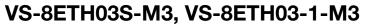
Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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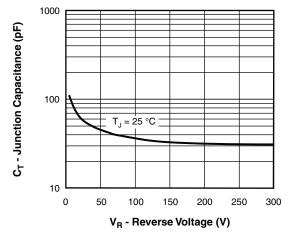


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

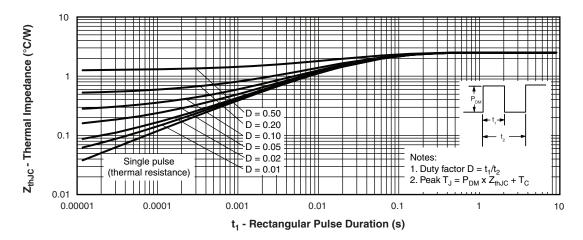
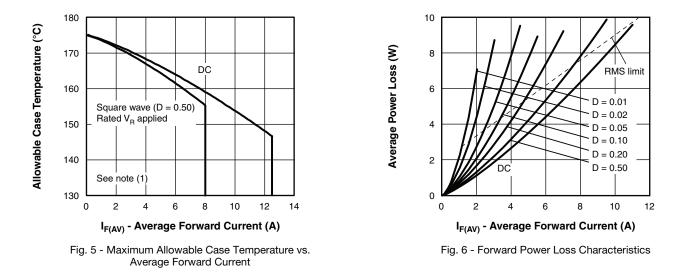


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics



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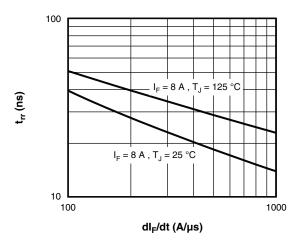
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Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt



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- <sup>(1)</sup> Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6); Pd<sub>REV</sub> = inverse power loss =  $V_{R1} \times I_R$  (1 - D);  $I_R$  at  $V_{R1}$  = rated  $V_R$

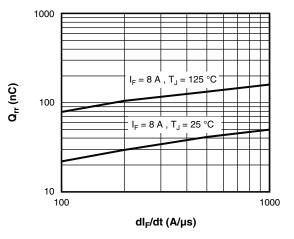


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

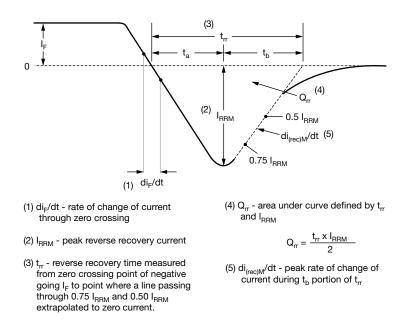
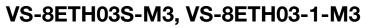


Fig. 9 - Reverse Recovery Waveform and Definitions

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### Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

Device code	VS-	8	Е	т	н	03	S	TRL	-МЗ
			<u> </u>		<u> </u>				
	(1)	(2)	(3)	$\begin{pmatrix} 1\\ 4 \end{pmatrix}$	(5)	(6)	(7)	(8)	(9)
	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$	$\bigcirc$
	1 - Vishay Semiconductors product								
	2 - Current rating (8 A)								
	3 - E = single diode								
	4 -	• T =	TO-220	, D <sup>2</sup> PAł	K (TO-26	63AB)			
	5 -	• H=	hyperfa	ast rectif	ier				
	6 -	Vol	tage rati	ng (03 =	= 300 V)				
	7 -	• S	= D <sup>2</sup> PA	K (TO-2	63AB)				
		• -1	= TO-2	62AA					
	8 -	• N	one = tu	ibe (50 p	oieces)				
	<ul> <li>TRL = tape and reel (left oriented, for D<sup>2</sup>PAK (TO-263AB) packag</li> </ul>								
	• TRR = tape and reel (right oriented, for D <sup>2</sup> PAK (TO-263AB) packa								
	9 -	- Env	/ironmei	ntal digi	t:				
		-M3	3 = halo	gen-free	e, RoHS	-compli	ant, an	d termir	nations le

ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-8ETH03S-M3	50	Antistatic plastic tubes					
VS-8ETH03STRL-M3	800	13" diameter plastic tape and reel					
VS-8ETH03STRR-M3	800	13" diameter plastic tape and reel					
VS-8ETH03-1-M3	50	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164				
	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444				
	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				

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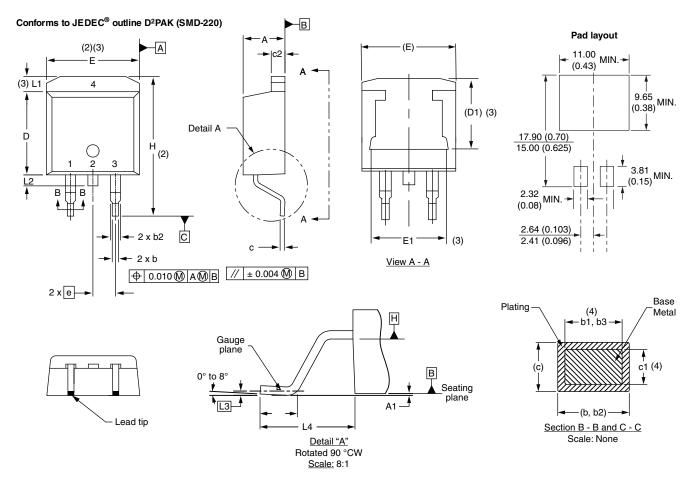


# **Outline Dimensions**

**Vishay Semiconductors** 

D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



	ETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES		
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES		STINDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only

<sup>(5)</sup> Datum A and B to be determined at datum plane H

<sup>(6)</sup> Controlling dimension: inches

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-263AB

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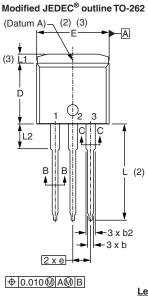


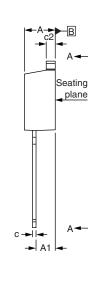
# **Outline Dimensions**

**Vishay Semiconductors** 

# **TO-262AA**

#### **DIMENSIONS** in millimeters and inches



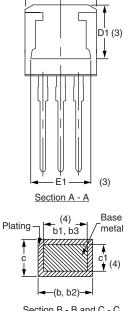


Lead assignments

Lead tip



1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode



F

Section B - B and C - C Scale: None

SYMBOL	MILLIN	IETERS	INC	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	) BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

 (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
 (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

<sup>(4)</sup> Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches Outline conform to JEDEC<sup>®</sup> TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), (6) L1 (max.), L2 (min., max.)

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